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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/666,434	09/18/2003	Hung Liao	100111692-2	8305
759	50,25,200		EXAM	INER
HEWLETT-PACKARD COMPANY Intellectual Property Administration			LEE, HSIEN MING	
P. O. Box 27240			ART UNIT	PAPER NUMBER
Fort Collins, Co	O 80527-2400		2823	
			DATE MAILED: 03/29/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

			A
	Application No.	Applicant(s)	
	10/666,434	LIAO ET AL.	
Office Action Summary	Examiner	Art Unit	
	Hsien-ming Lee	2823	
The MAILING DATE of this communication appeariod for Reply	opears on the cover sheet with t	he correspondence address	
A SHORTENED STATUTORY PERIOD FOR REP	LY IS SET TO EXPIRE 3 MON	TH(S) FROM	
THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).		be timely filed) days will be considered timely. from the mailing date of this communicat DONED (35 U.S.C. § 133).	ion.
Status			
1)⊠ Responsive to communication(s) filed on 26.	January 2005.		
· _ ·	is action is non-final.	•	
3) Since this application is in condition for allow		, prosecution as to the merits	is
closed in accordance with the practice under	·		
Disposition of Claims			
4) Claim(s) 8-13,16,17 and 22-24 is/are pending	g in the application.		
4a) Of the above claim(s) is/are withdra	awn from consideration.		
5)⊠ Claim(s) <u>8-13,16 and 17</u> is/are allowed.			
6)⊠ Claim(s) <u>22-24</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers	. «		
9) The specification is objected to by the Examir	ner.		
10) The drawing(s) filed on is/are: a) ac	cepted or b) objected to by	the Examiner.	
Applicant may not request that any objection to the	e drawing(s) be held in abeyance.	See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the corre	ction is required if the drawing(s) i	s objected to. See 37 CFR 1.121	l(d).
11) The oath or declaration is objected to by the E	Examiner. Note the attached O	ffice Action or form PTO-152.	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of:	n priority under 35 U.S.C. § 11	9(a)-(d) or (f).	
1.☐ Certified copies of the priority documer	ate have been received		
Certified copies of the priority documer Certified copies of the priority documer		ication No	
Copies of the certified copies of the pri			
application from the International Bure	-	cived in this Hational Otage	
* See the attached detailed Office action for a lis	, , , ,	eived	
		HBIEN-MING LEE	
		PRIMARY EXAMPLE	
Attachment(s)		3 pepe	ns
1) Notice of References Cited (PTO-892)	4) Interview Sumi		
 Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/06 		ail Date nal Patent Application (PTO-152)	
 Information Disclosure Statement(s) (PTO-1449 or PTO/SB/06 Paper No(s)/Mail Date 	6) Other:	· · · · · · · · · · · · · · · · · · ·	

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DETAILED ACTION

Remarks

1. Applicant's cancellation to claims 1-7, 14-15 and 18-21 is acknowledged. Claims 22-24 are newly added. Thus, claims 8-13, 16-17 and 22-24 are pending in the application.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 22-24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Havemann et al. (US 5,059,546) in view of Nishizawa et al. (US 4,329,625).

In re claim 22, Havemann et al., in Figs. 9-10 and related text, teach the claimed process for manufacturing a BiMOS microcircuit, comprising:

- forming a base 44 (Fig.9);
- forming a collector 34 (Fig.9); and
- forming an emitter 74 of a silicide on the base 44 (Fig.9); and
- forming an emitter contact 100 to the emitter 74 (Fig.9).

Havemann et al. do not teach forming the emitter of a group III-VI semiconductor.

Nishizawa et al., however, teach forming the emitter of a group III-VI semiconductor, comprising indium oxide (col. 8, lines 52-55), wherein indium is a group III element and oxygen is a group VI element.

Therefore, it would have been obvious to one of the ordinary skill in the art, at the time of the invention was made, to form the emitter of group III-VI semiconductor, as taught by Nishizawa et al., in the method of Havemann et al., since by this manner it would satisfactory form a bipolar photo-transistor.

In re claim 23, Havemann et al also teach forming a base 44 of a p-type semiconductor material (Fig.9 and col. 4, line 28) and forming a collector 34 of an n-type semiconductor material (Fig.9 and col. 4, lines 6-7).

In re claim 24, Havemann et al also teach forming a base 44 of a p-type semiconductor material (Fig.9 and col. 4, line 28) and forming a collector 34 of an n-type semiconductor material (Fig.9 and col. 4, lines 6-7; and further comprises doping the group III/VI semiconductor, as integrating the method of Havemann et al with the method of Nishizawa et al..

Allowable Subject Matter

- 4. Claims 8-13 and 16-17 are allowed.
- 5. The following is a statement of reasons for the indication of allowable subject matter:

None of prior art of record, either alone or combination teaches the group III/VI semiconductor is selected from the group consisting of GaS, GaSe, GaTe, InS, InSe, InTe and TIS.

Conclusion

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hsien-ming Lee whose telephone number is 571-272-1863. The examiner can normally be reached on Tuesday-Thursday ($8:00 \sim 6:00$).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 571-272-1855. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Hsien-ming Lee Primary Examiner Art Unit 2823

March 22, 2005

HSIEN-MING LEEP PRIMARY EXAMINED 3/2/2005